



Laser Interferometer Gravitational-Wave Observatory

Introduction to Fabry-Perot Cavities and 40m Power-Recycling Interferometer

M. Rakhmanov and J. Logan

*California Institute of Technology
Pasadena, California*

lecture notes from LIGO Science Seminar
March 1997

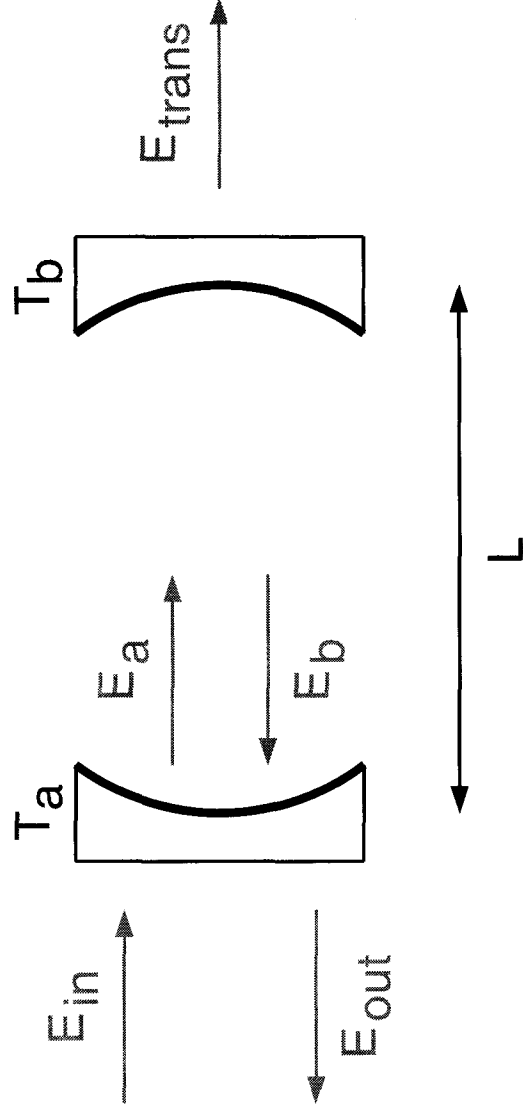
Overview

- The physics of Fabry Perot cavities
 - ›› setting the scene for recycling
- Recycling at the 40m: Optical Design and Choice of Parameters
 - ›› coupled cavities
 - ›› choice of optical parameters
- Displacement Calibration and Shot Noise

The Physics of Fabry Perot Cavities

- definitions of standard parameters
- cavity DC response
- phase modulation
- reflection locking

Fields in Fabry Perot Cavities



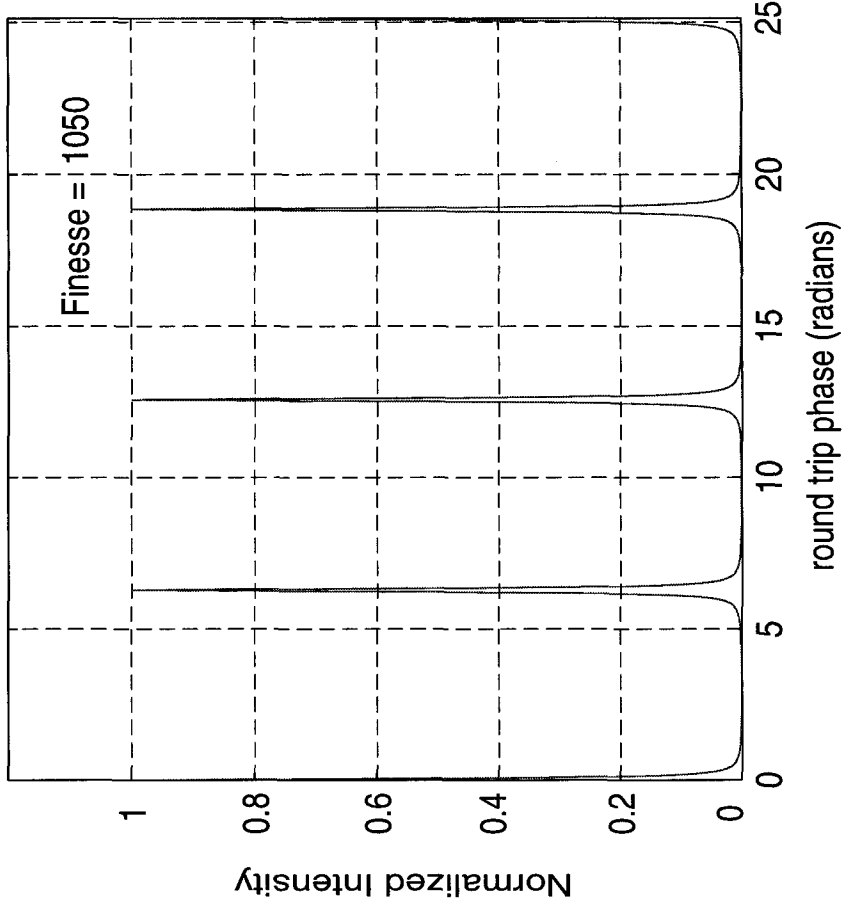
The transmitted light power

$$\frac{P_{trans}}{P_{in}} = \frac{T_a T_b}{(1 - r_a r_b)^2 + 4 r_a r_b \sin^2(\phi/2)}$$

Light in the cavity experiences a round trip phase of ϕ . On
RESONANCE

$$\phi = 2n\pi \text{ or equivalently } f = \frac{c}{2L}n$$

Transmitted Light as a function of cavity offset



The transmission peaks are spaced in frequency by

$$\frac{c}{2L} = \text{Free Spectral Range of the Cavity}$$

The cavity finesse is defined to be

$$\text{Finesse} = \frac{\text{Separation of Adjacent Transmission Peaks}}{\text{Full width of peak at half maximum}} = \frac{\pi \sqrt{r_a r_b}}{(1 - r_a r_b)}$$



Another useful quantity is the Co-efficient of Finesse

$$F = \frac{4r_a r_b}{(1 - r_a r_b)^2} = \frac{4(\text{Finesse})^2}{\pi^2}$$

Some typical numbers:

Arm cavity	FSR (MHz)	Finesse	δf (Hz)
40m recombined	3.9	12,770	305
40m recycling	3.9	1050	3700
LIGO	0.04	206	180

Arm cavity	Ta	Tb	L
40m recombined	280 ppm	12 ppm	100 ppm
40m recycled	5750 ppm	12 ppm	100 ppm
LIGO	0.03	10 ppm	30 ppm



Cavity Reflectivity

$$\frac{E_{out}}{E_{in}} = \frac{r_a - r_b(1 - L_a)e^{i\phi}}{1 - r_a r_b e^{i\phi}}$$

-> the cavity looks like a mirror of variable reflectivity. At resonance

$$r_{cavity} = \left(\frac{E_{out}}{E_{in}} \right)_{\phi=0} = \frac{r_a - r_b(1 - L_a)}{1 - r_a r_b}$$

For small deviations from resonance

$$C_o = \left| \frac{\partial}{\partial \phi} \left(\frac{E_{out}}{E_{in}} \right) \right|_{\phi=0} = \frac{T_a r_b}{(1 - r_a r_b)^2}$$

This is the DC cavity response. Typical numbers:

Arm cavity	r_{cavity}	C_o
40m recombined	-0.138	4626
40m recycled	-0.929	645
LIGO arm cavity	-0.995	130

Coupling of Cavity

$$\left(\frac{E_{out}}{E_{in}} \right)_{\phi=0} = \frac{r_a - r_b(1 - L_a)}{1 - r_a r_b}$$

Optimal Coupling occurs when $E_{out} = 0$. For small transmission and losses this occurs when

$$T_a = T_b + L_a + L_b$$

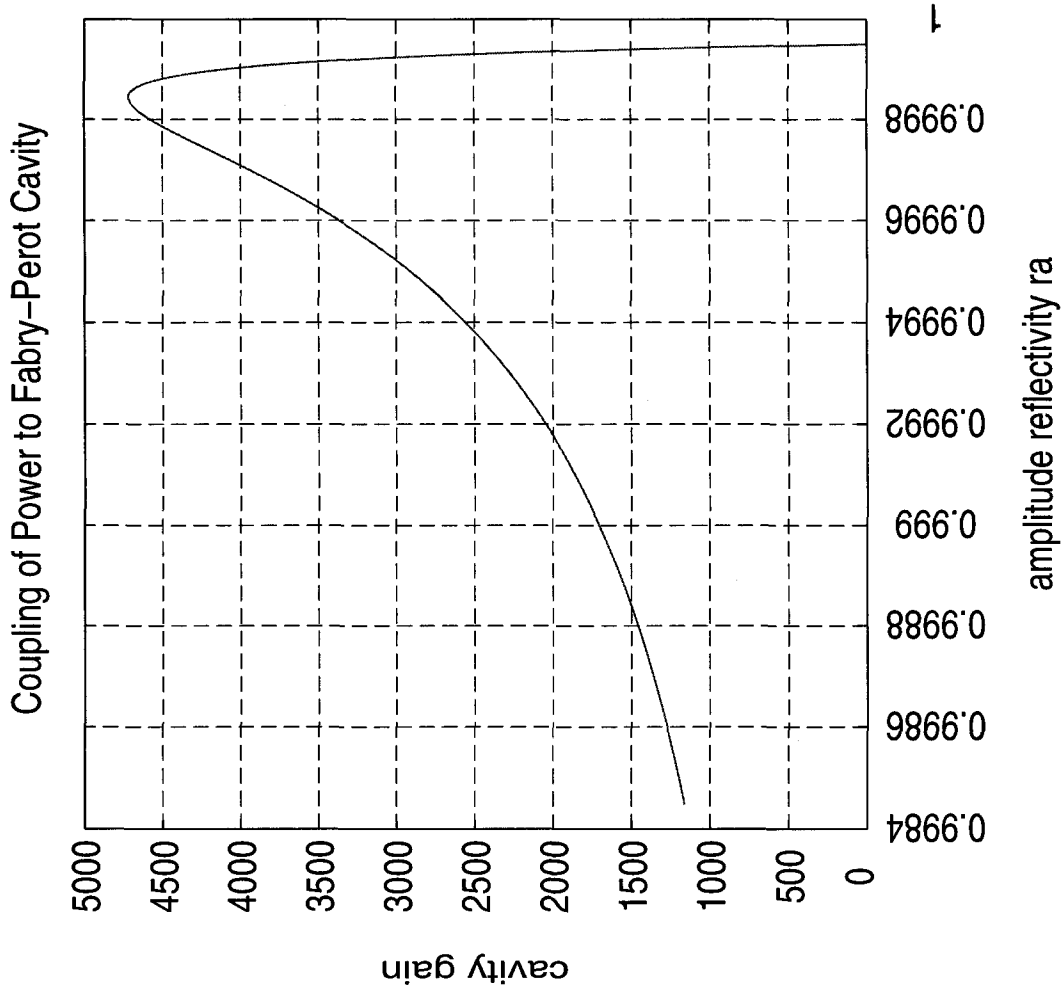
If $T_a < T_b + L_a + L_b$ then E_{out} is +ve i.e. in phase with incident light - cavity is undercoupled.

If $T_a > T_b + L_a + L_b$ then E_{out} is -ve i.e. out of phase with incident light - cavity is overcoupled.

Cavity Gain

On resonance the optical gain of the cavity is:

$$G = \left| \frac{E_a}{E_{in}} \right|^2 = \frac{T_a}{(1 - r_a r_b)^2}$$



Optimal coupling => maximum cavity gain

$$G_{opt} \approx \frac{1}{T_b + L_a + L_b}$$

cavity response for small changes in ϕ

$$C_o = Gr_b$$

∴ for maximum cavity response want to be (close to) optimally coupled

Cavity Visibility

Cavity visibility

$$V = 1 - \frac{P_{min}}{P_{max}}$$

where P_{min} and P_{max} is the in lock and out of lock power respectively reflected by the arm.

Note that since in general only a fraction M of the input laser light, P_o , is modematched to the cavity

$$P_{min} = R_{cavity} M P_o + (1 - M) R_a P_o$$

$$P_{max} = R_a P_o$$

∴ for low modulation depth (see later)

$$V = M \left(1 - \frac{R_{cavity}}{R_a} \right)$$

For 40m, $M \sim 0.9$,

Arm cavity	R_{cavity}	Ta	V
40m recombined	0.019	280 ppm	0.88
40m recycled	0.86	5750 ppm	0.12

Phase Modulation and Signal for Locking Fabry Perot Cavity

Simple Example
Phase Modulation Sidebands
Phase Modulation Parameters
Bessel Functions
Sideband Initial Phases
Sideband Propagation
Power in the Sidebands
Intensity on the Photodiode
Photodiode Responsivity
Photodiode Quantum Efficiency
Photodiode Output
Demodulation
Signal
Signal's Maximum
Optimal Modulation

Simple Example

Frequencies: $\omega_0, \omega_0 + \Omega$

Field incident on F-P cavity

$$E = E_0 e^{i\omega_0 t} (1 + a e^{i\Omega t})$$

Field after the reflection

$$E = E_0 e^{i\omega_0 t} (\rho(x) + a e^{i\Omega t})$$

Intensity at the photodiode

$$|E|^2 = E_0^2 (2a \operatorname{Im}\{\rho(x)\} \sin \Omega t \dots)$$

Demodulation picks up 1Ω -component:

$$V \sim \operatorname{Im}\{\rho(x)\}.$$

Can lock on the sideband: less signal, wrong sign

Phase Modulation Sidebands

Frequencies: $\omega_0 + \Omega$, ω_0 , $\omega_0 - \Omega$

Field after Pockel Cell

$$E = E_0 e^{i\omega_0 t} e^{i\Gamma \sin \Omega t}.$$

Expansion

$$1 + i\Gamma \sin \Omega t = 1 + \frac{\Gamma}{2} e^{i\Omega t} - \frac{\Gamma}{2} e^{-i\Omega t}$$

Same result

$$V \sim \text{Im}\{\rho(x)\}.$$

Phase Modulation Parameters

Modulation frequency

$$\Omega = 2\pi f_{mod}$$

Modulation wavelength

$$\lambda_{mod} = \frac{c}{f_{mod}}$$

40m and LIGO Parameters

	$f_{mod}(\text{MHz})$	$\lambda_{mod}(\text{m})$
Recombined 40m	12.3	24.4
Recycled 40m	32.7	9.18
LIGO	24.5	12.2

Bessel Functions

Fourier expansion

$$e^{i\Gamma \sin \Omega t} = \sum_{n=-\infty}^{\infty} J_n(\Gamma) e^{in\Omega t}$$

where $J_n(\Gamma)$ are Bessel functions

Γ - Modulation Index

There is infinite number of sidebands

Frequencies

$$\omega_n = \omega_0 + n \Omega$$

The amplitudes

$$E_n = J_n(\Gamma) E$$

Sideband Initial Phases

Bessel functions with negative index flip sign

$$J_{-n}(\Gamma) = (-1)^n J_n(\Gamma)$$

General rule:

Upper sidebands are all positive

Lower even number sidebands are positive

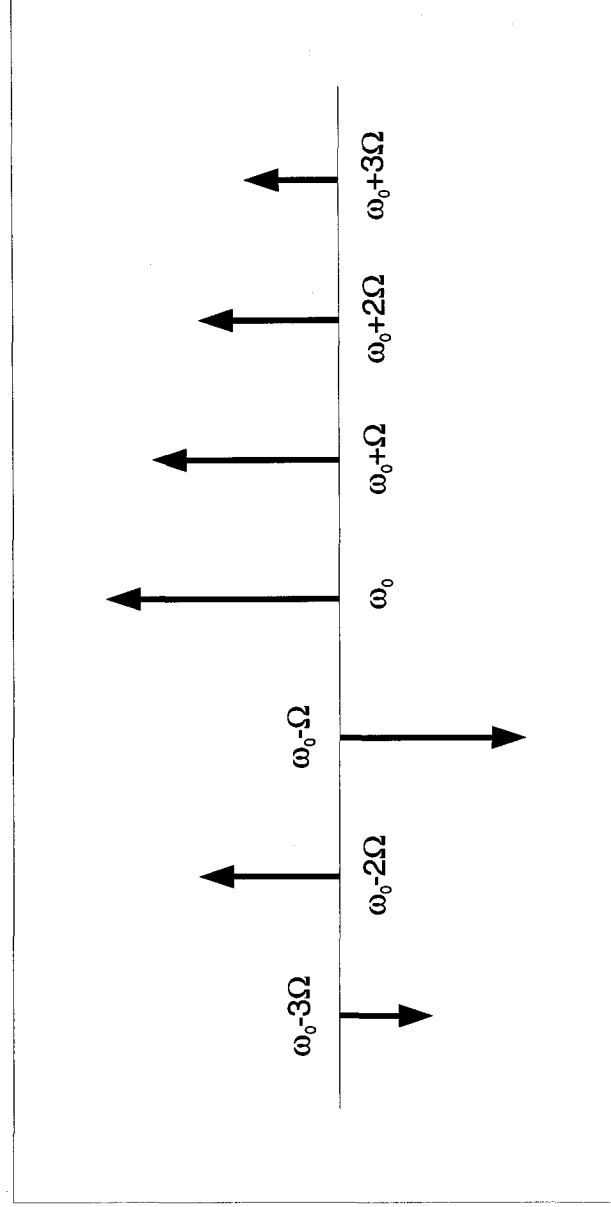
Lower odd number sidebands are negative

Example:

$$E_{-1} = -E_{+1},$$

$$E_{-2} = +E_{+2}$$

Figure 1: Sideband Initial Phases



Sideband Propagation

Picture 1

Sidebands have different frequencies.

For propagation in positive z -direction

$$E_0 = E J_0 e^{i\omega_0(t - \frac{z}{c})},$$

$$E_n = E J_n e^{i\omega_n(t - \frac{z}{c})}$$

Picture 2

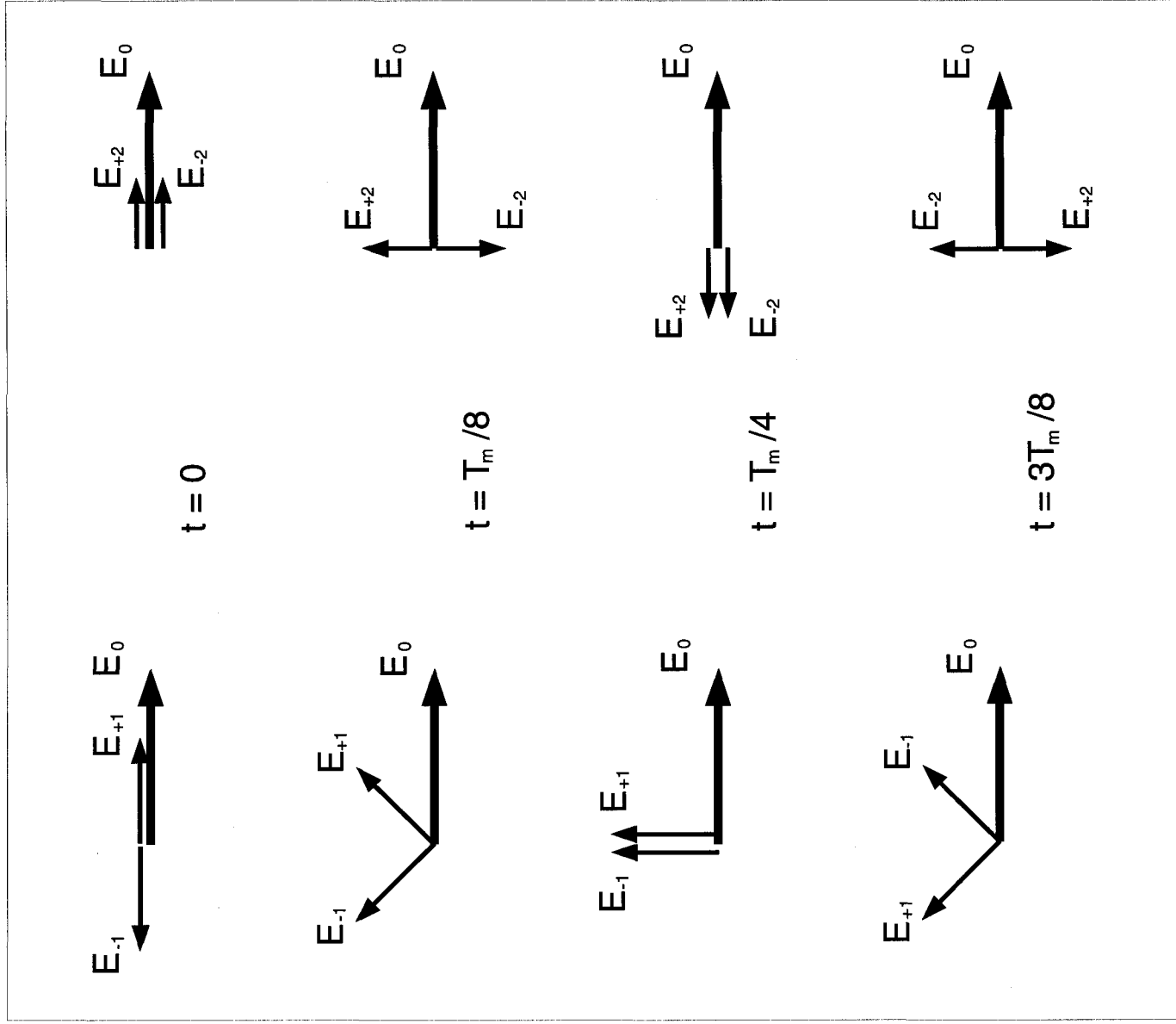
Sidebands have the same frequency as the carrier, but their phases *slowly* change with time

$$E_n = E J_n e^{i\omega_0(t - \frac{z}{c})} e^{iU_n}$$

$U_n(z, t)$ is the phase of the n th-sideband relative to carrier

$$U_n = n \Omega \left(t - \frac{z}{c} \right).$$

Figure 1: Phasor Diagram for 1st and 2nd Order Sidebands*



Power in the Sidebands

Modulation index, Γ , can be found from measurements of sideband power.

The power in n th-sideband

$$P_n = P J_n^2(\Gamma)$$

The measurements are done using optical spectrum analyzer.

Resolving sidebands is necessary for accurate measurements of contrast defect.

Fig. Spectrum of Light (Gamma = 1.0)

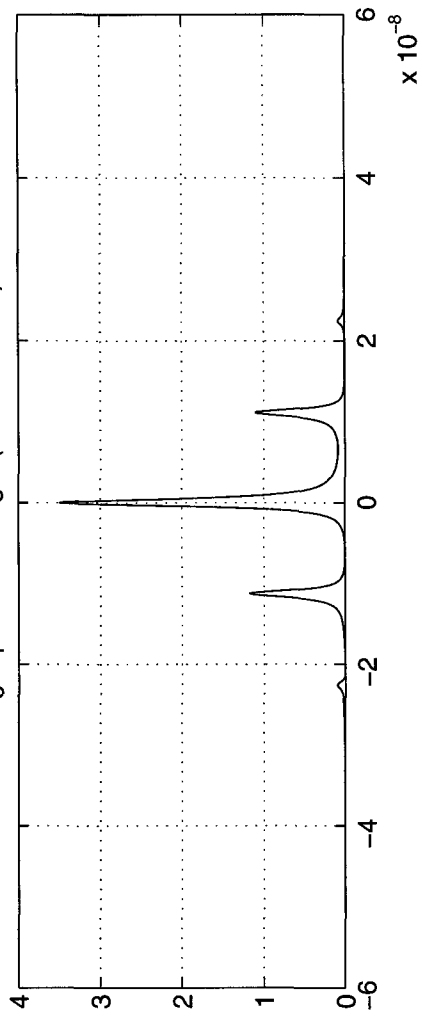
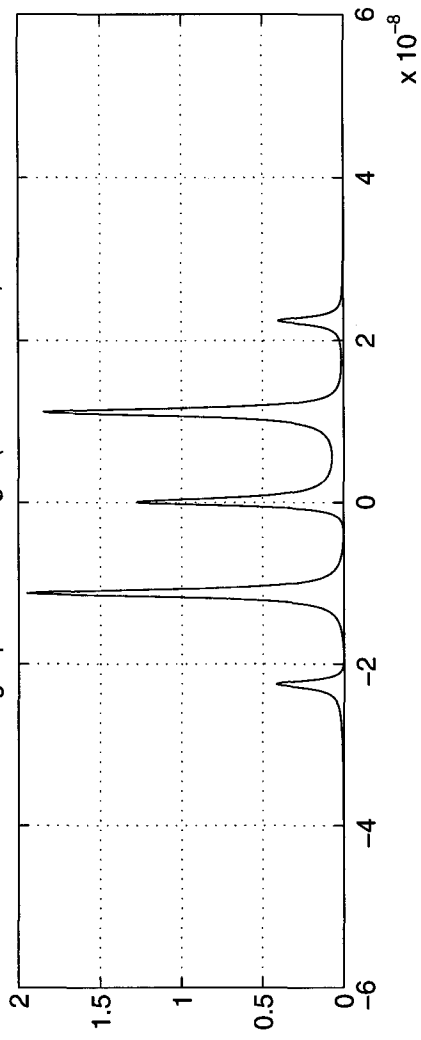


Fig. Spectrum of Light (Gamma = 1.6)



Intensity at the Photodiode

If cavity is on resonance intensity is constant in the first order.

If cavity deviates from resonance the intensity is modulated

$$P = A_0 + 2A_1 \cos \Omega t + 2B_1 \sin \Omega t.$$

Either A_1 or B_1 is proportional to deviation of cavity from resonance.

The coefficients are

$$A_0 = |E_0|^2 + |E_{+1}|^2 + |E_{-1}|^2,$$

$$A_1 = \operatorname{Re} \{ E_0^* (E_{+1} + E_{-1}) \},$$

$$B_1 = \operatorname{Im} \{ E_0^* (E_{+1} - E_{-1}) \}.$$

Photodiode Responsivity

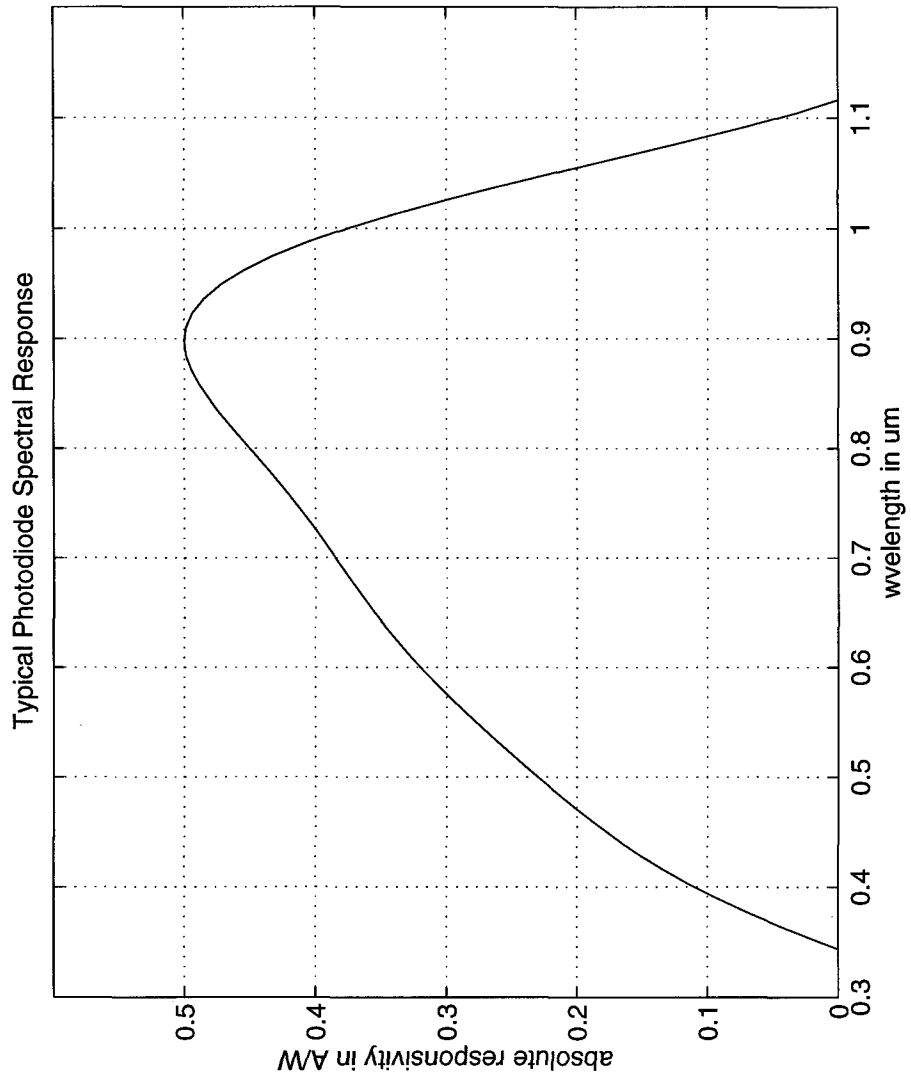
At the photodiode the intensity of light is converted to the photocurrent

$$I(t) = \sigma P(t)$$

σ is the responsivity the photodiode

For the green light $\lambda = 514.5$ nm the responsivity is

$$\sigma = 0.25 \text{ A/W}$$



Photodiode Quantum Efficiency

Each photon carries energy $h\nu$.

Intensity of light = total energy carried by photons in 1 sec

$$P = h\nu N_{ph}$$

Photocurrent = total charge carried across the photodiode in 1 sec

$$I = eN_e$$

Quantum efficiency of the photodiode $\kappa < 1$

$$N_e = \kappa N_{ph}$$

Photodiode responsivity

$$\sigma = \frac{\kappa e}{h\nu}$$

The choice above corresponds to $\kappa = 0.6$

Photodiode Output

Photodiode has resonant circuit

$$\tilde{Z}(\omega) = \frac{R}{1 + i\omega RC(1 - \frac{\omega_r^2}{\omega^2})}$$

The resonance frequency $\omega_r = 1/\sqrt{LC}$ is tuned to coincide with the modulation frequency Ω .

$C = 70$ pF (under bias),

L is tuned inductance,

$R \approx 600$ Ohm

Photodiode output

$$V_{pd}(t) = R I(t)$$

Demodulation

Demodulation signal $D(t)$ is a square wave.

β adjustable phase

Approximation:

leave only the first term of the Fourier series

$$D(t) = \frac{4}{\pi} \sin(\Omega t + \beta).$$

Coefficient $\frac{4}{\pi}$ is important for comparison with calibration.

Mixer output

$$V = V_{pd}(t) D(t)$$

Signal

In stationary approximation

$$V(x) = V_0 \frac{\sin 2kx}{1 + F \sin^2 kx}$$

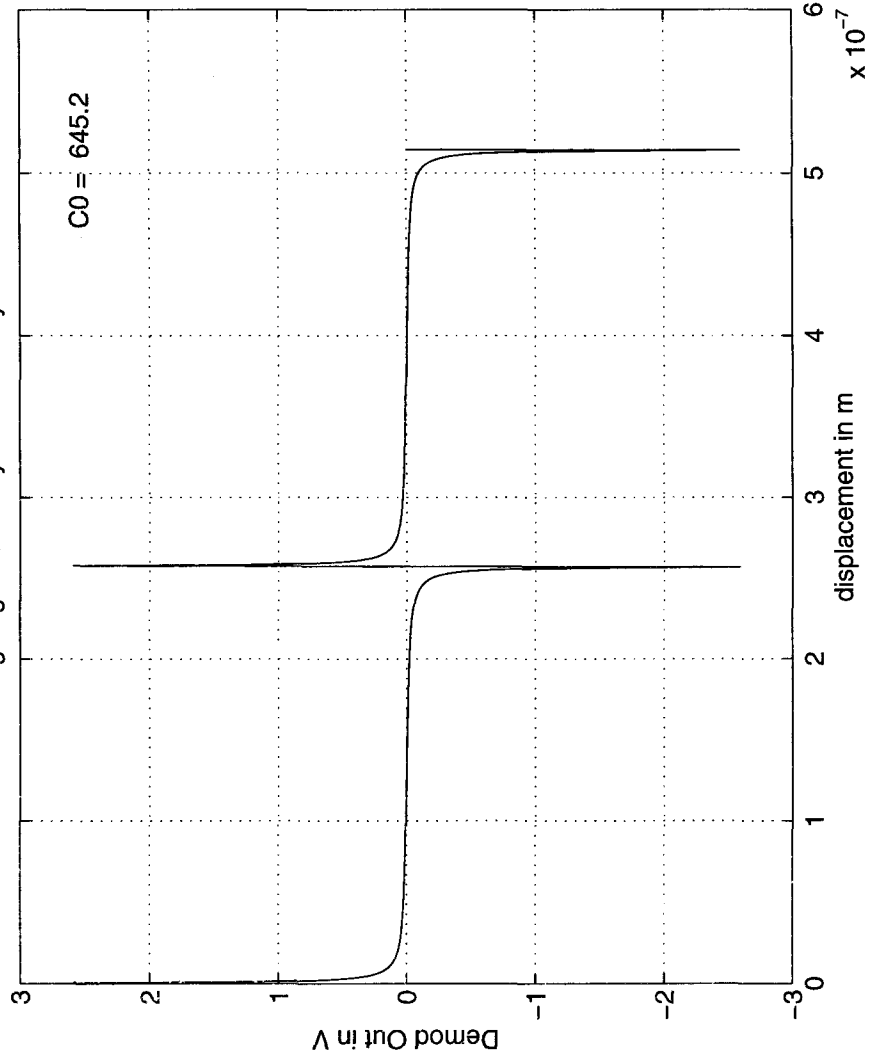
40m recycling arm cavity $F = 4.48 \times 10^5$

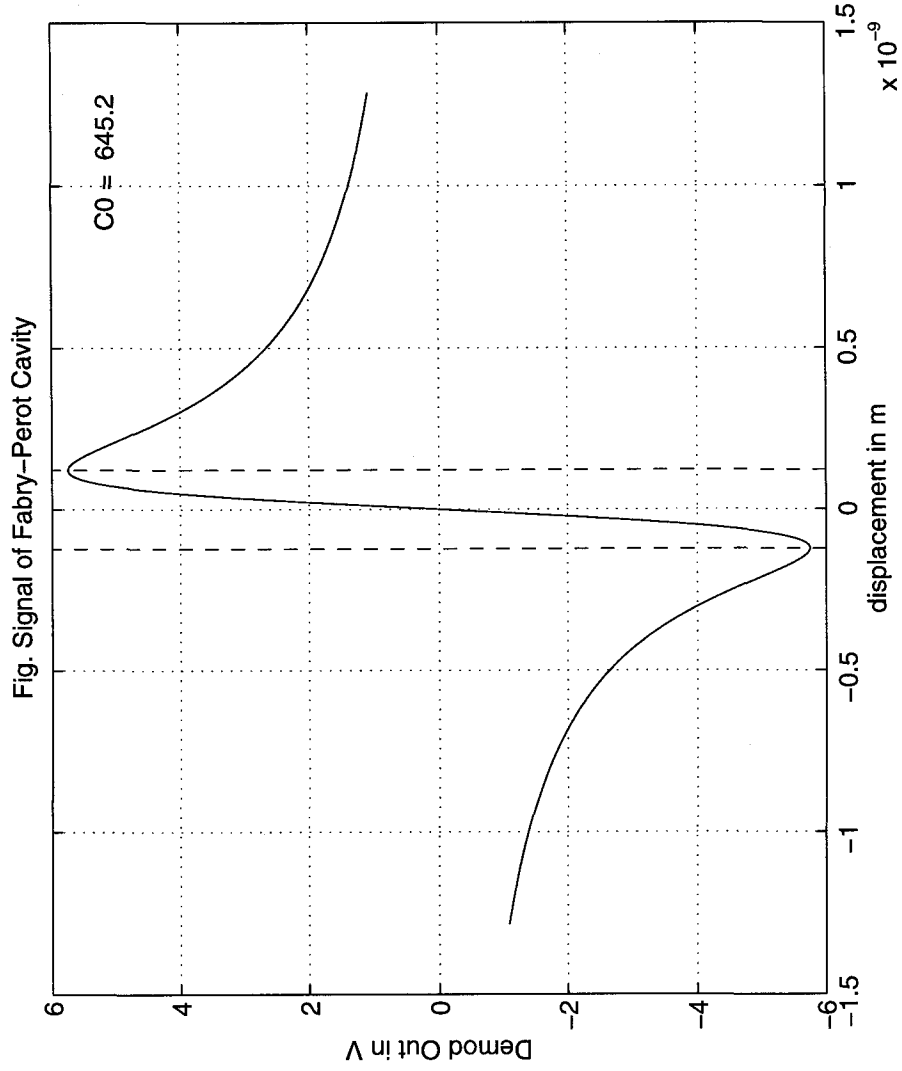
The magnitude of the signal is defined by the constant

$$V_0 = \frac{4}{\pi} R \sigma P M J_0 J_1 C_0$$

$$2 k V_0 = 160 \text{ V/nm}$$

Fig. Signal of Fabry-Perot Cavity





Maximum of Signal

Fine tuning

Signal as a function of modulation index

$$V_0 \sim J_0(\Gamma) J_1(\Gamma)$$

Maximum of the function is at

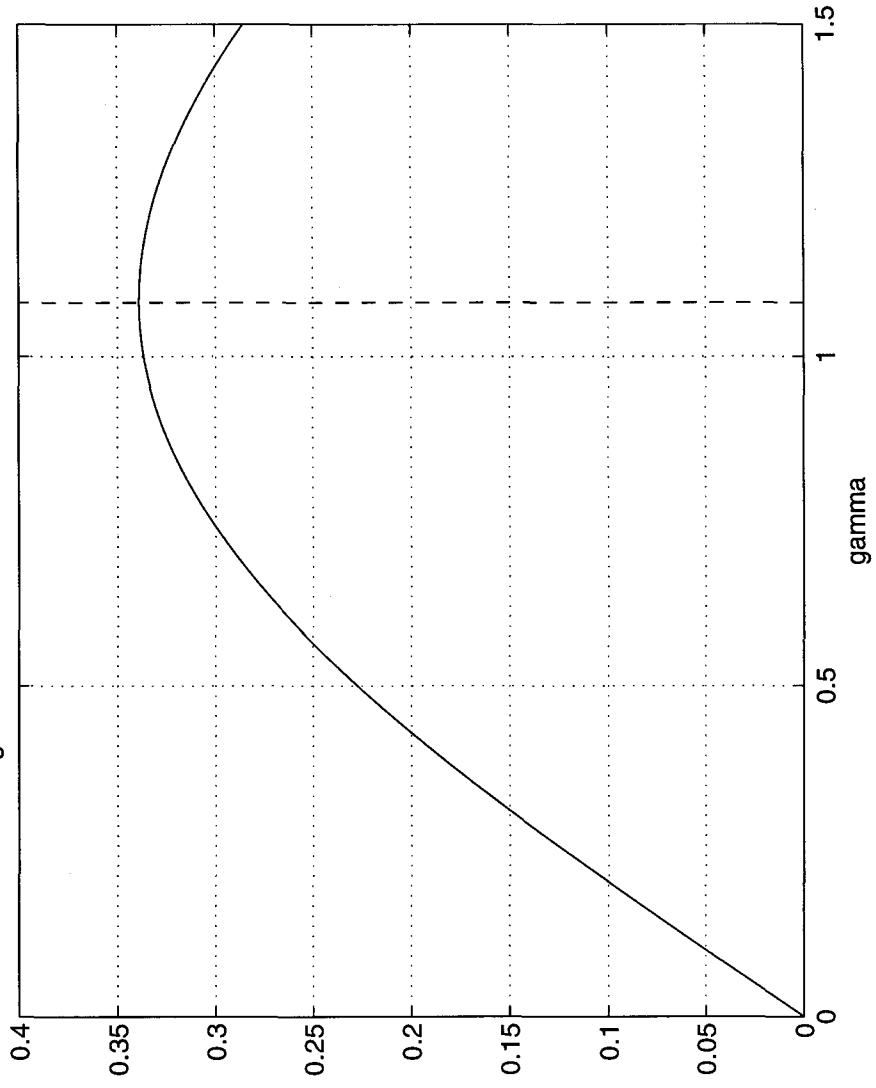
$$\Gamma_1 = 1.08$$

It corresponds to

$$\frac{J_1^2}{J_0^2} = 0.43$$

Beyond this point there is no increase in the signal

Fig. $J_0 * J_1$ as Function of Modulation Index



Optimal Modulation

If we are shot noise limited then the important signal to noise ratio is

$$K(\Gamma) = \frac{J_0 J_1}{\sqrt{\rho^2 J_0^2 + 2J_1^2}}$$

For single Fabry-Perot cavity ρ^2 is a square of static cavity reflectivity

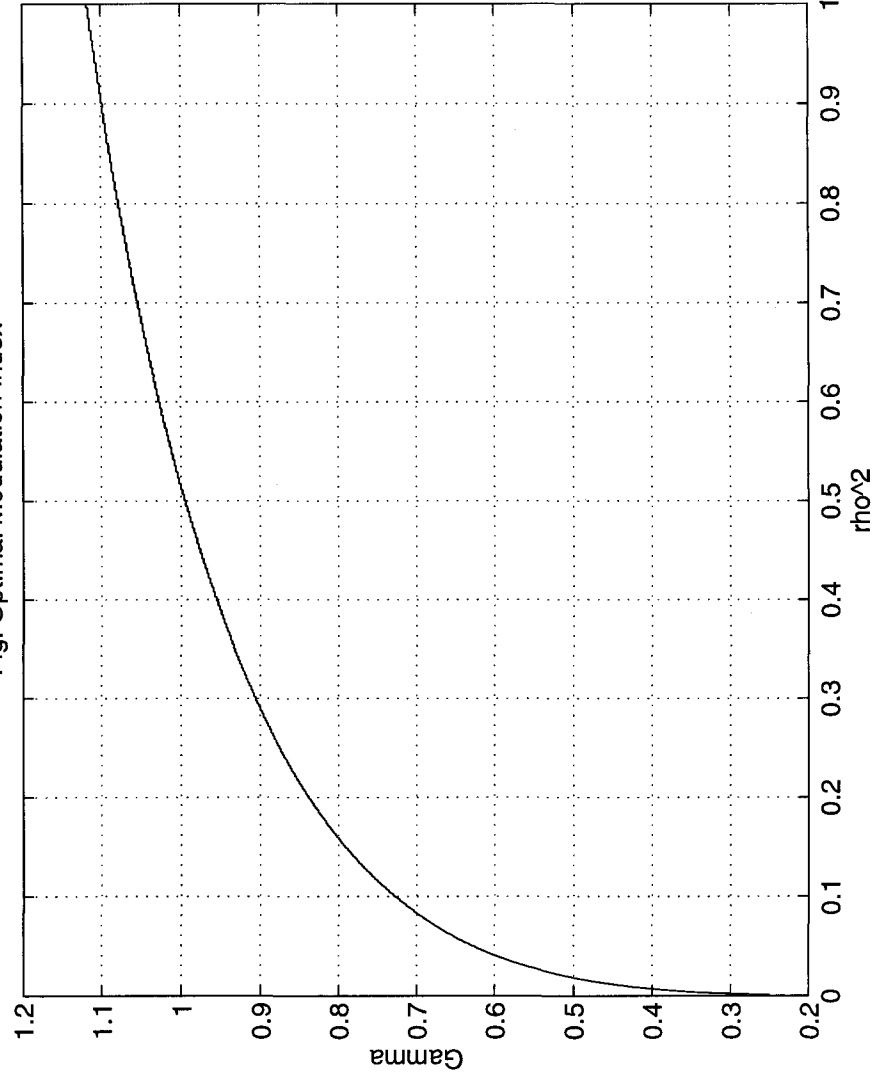
For recycled interferometer ρ^2 is contrast defect
In general the range $\rho^2 < 1$

For any particular ρ^2 maximum can be found numerically. This will define optimal modulation index Γ_{opt} .

Γ_{opt} as a function of ρ^2 is found numerically

$$\Gamma_{opt} = \Gamma_{opt}(\rho^2)$$

Fig. Optimal Modulation Index



Recycling II: Optical Design and Choice of Parameters

- the use of an asymmetric Michelson
- choice of modulation frequency
- choice of mirror reflectivities
- cavity dynamics
 - ringdowns
 - transfer functions

Frontal / Schnupp Modulation

- Have already seen the use of modulation to control a single Fabry Perot cavity

How do we apply this principle to a system with several degrees of freedom?

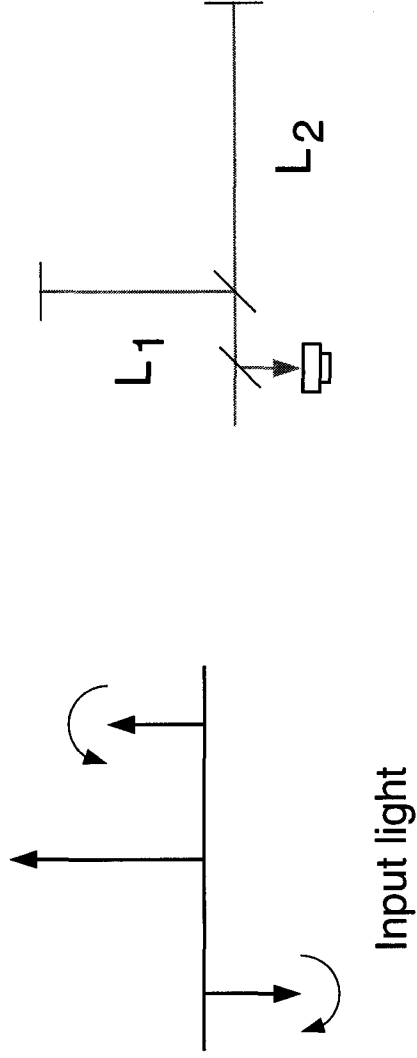
Modulate the light immediately before it enters the interferometer - called frontal or Schnupp modulation.

- Need an asymmetric Michelson.

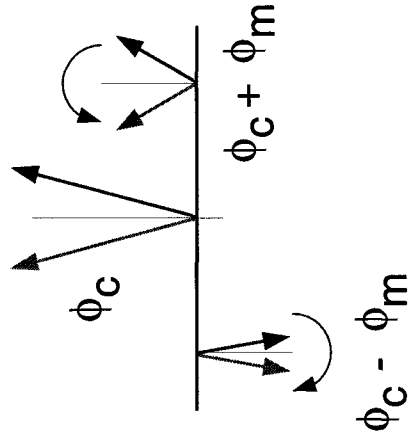
Why?

- Asymmetric Michelson is dispersive \therefore whilst carrier light appears at only one port, sidebands are transmitted to both ports.

e.g. consider control of beamsplitter for simple Michelson:



Light from 1 has phase retarded
 Light from 2 has phase advanced



If $\phi_c \neq 0$ then one sideband is larger than the other \therefore locking is equivalent to equalising the sideband heights.

Optimal Asymmetry

The optimal asymmetry is calculated by considering the shot noise limited sensitivity of the GW. It is achieved for

$$\cos\left(\frac{2\pi\delta}{\lambda_{mod}}\right) = r_R^T P$$

For the 40m parameters:

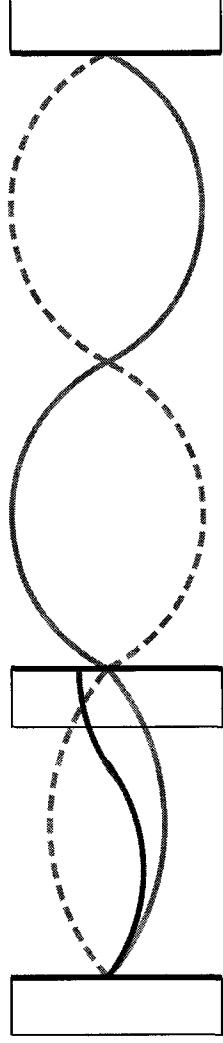
$$\delta_{opt} = 67 \text{ cm}$$

Due to space considerations

$$\delta = 54 \text{ cm}$$

Choice of Modulation Frequency

- Sidebands + carrier are resonant in the recycling cavity, only carrier is resonant in the arms.



- Carrier has phase change of π between light entering and leaving arm \therefore for carrier resonant in the recycling cavity $\phi_c = 2k\pi$
- For sidebands to be resonant in the recycling cavity, we require a π phase change i.e.

$$\phi_s = \phi_c + \phi_{\text{mod}} = 2n\pi + \pi$$

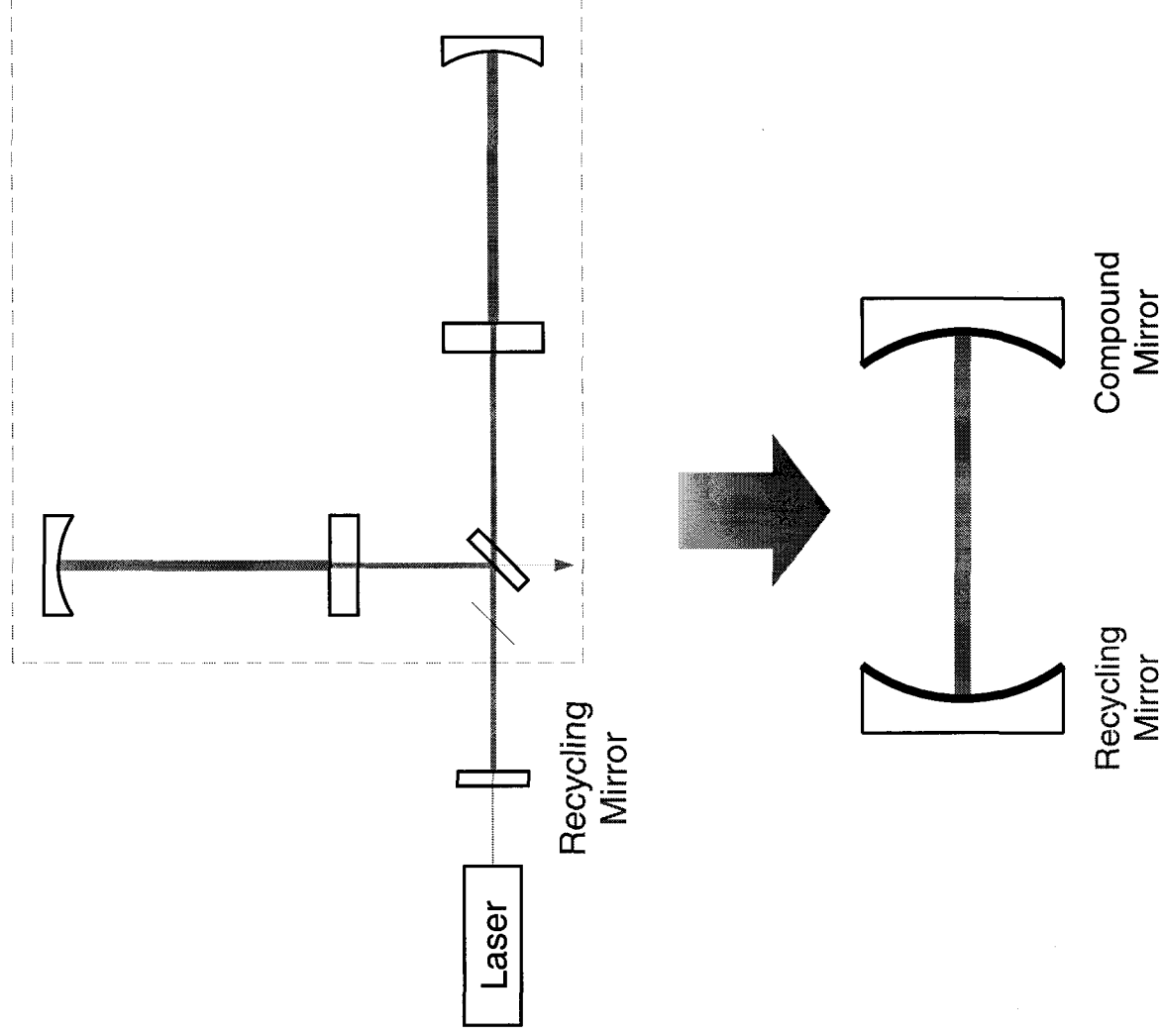
$$\phi_{\text{mod}} = \frac{4\pi l_R}{\lambda_{\text{mod}}} = 2m\pi + \pi$$

$$l_r = \frac{\lambda_{\text{mod}}}{2} \left(m + \frac{1}{2} \right)$$

From space considerations at 40m, $l_r = 2.3\text{m}$

$$\Rightarrow f_{\text{mod}} = 32.7 \text{ MHz}$$

Recycling: Choice of Mirror Parameters



Recombined Interferometer as a Compound Mirror

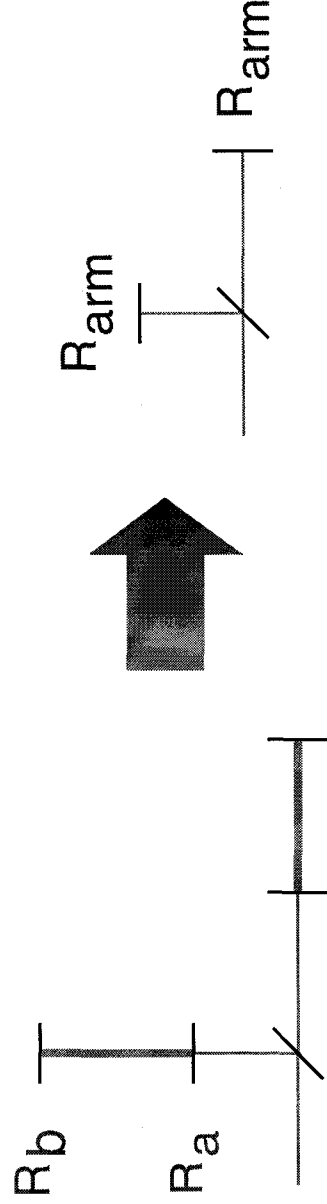
Recall, single FP cavity has a reflectivity

$$R_{\text{cavity}} = \left[\frac{r_a - r_b(1 - L_a)e^{i\phi}}{1 - r_a r_b e^{i\phi}} \right]^2$$

In reality only a fraction, M , of the input power is modematched to the cavity $\therefore (1-M)$ of the light reflects directly off the front mirror. Define

$$R_{\text{arm}} = MR_{\text{cavity}} + (1 - M)R_a$$

Thus we may reduce the recombined topology to



Contrast

The contrast of the interferometer is a measure of how perfectly light interferes at the beamsplitter:

$$C = \frac{P_B - P_D}{P_B + P_D}$$

P_D is minimum carrier power at dark port with both arms in lock. P_B is maximum carrier power at bright port with arms out of lock.

Some fraction, n , of carrier light recombining at the beamsplitter leaks out of the dark port

